



Jiangsu Weida Semiconductor Co., Ltd.

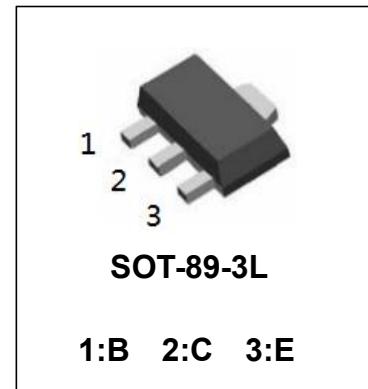
NPN Transistors

BCX54,BCX55,BCX56

(KCX54 ,KCX55,KCX56)

■ Features

- ◆ High current (max. 1A).
- ◆ Low voltage (max.80V).
- ◆ Package:SOT-89-3L.



■ Absolute Maximum Ratings Ta = 25°C

Parameter	Symbol	Rating	Unit
Collector-base voltage	BCX54	45	V
	BCX55	60	V
	BCX56	100	V
Collector-emitter voltage	BCX54	45	V
	BCX55	60	V
	BCX56	80	V
Emitter-base voltage	V _{EBO}	5	V
Collector current	I _C	1	A
Peak collector current	I _{CM}	1.5	A
Peak base current	I _{BM}	0.2	A
Total power dissipation	P _{tot}	1.3	W
Storage temperature	T _{stg}	-65 to +150	°C
Junction temperature	T _j	150	°C
Operating ambient temperature	T _{amb}	-65 to +150	°C
Thermal resistance from junction to ambient	R _{th(j-a)}	94	K/W
Thermal resistance from junction to solder point	R _{th(j-s)}	14	K/W

■ Electrical Characteristics Ta = 25°C

Parameter	Symbol	Testconditions	Min	Typ	Max	Unit
Collector cutoff current	I _{CBO}	V _{CB} = 30 V, I _E = 0			100	nA
		V _{CB} = 30 V, I _E = 0; T _j = 125 °C			10	uA



Jiangsu Weida Semiconductor Co., Ltd.

NPN Transistors

Emitter cutoff current	I _{EBO}	V _{EB} = 5 V, I _c = 0			100	nA
DC current gain	h _{FE}	I _c = 5 mA; V _{CE} = 2 V	63			
		I _c = 150 mA; V _{CE} = 2 V	63	250		
		I _c = 500 mA; V _{CE} = 2 V	40			
DC current gain BCX54-10,BCX55-10,BCX56-10 BCX54-16,BCX55-16,BCX56-16	h _{FE}	I _c = 150 mA; V _{CE} = 2 V	63	160		
		I _c = 150 mA; V _{CE} = 2 V	100	250		
Collector-emitter saturation voltage	V _{CE(sat)}	I _c = 500 mA; I _b = 50 mA			0.5	V
Base to emitter voltage	V _{BE}	I _c = 500 mA; V _{CE} = 2 V			1	V
Transition frequency	f _T	I _c = 10 mA; V _{CE} = 5 V; f = 100 MHz		130		MHz
DC current gain ratio of the complementary pairs	$\frac{h_{FE}}{h_{FE}}$	I _c = 150 mA; V _{CE} = 2V		1.3	1.6	

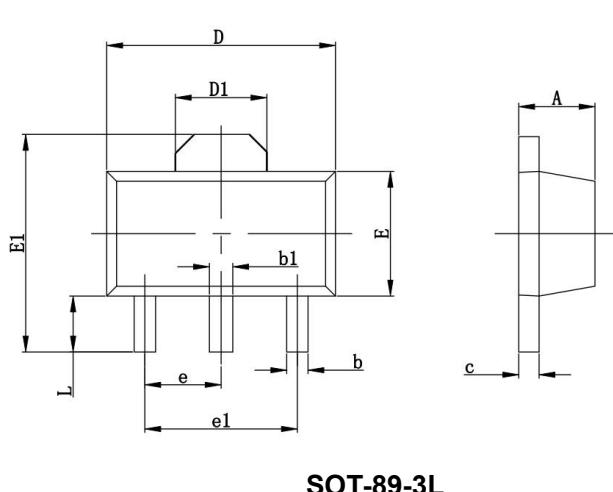
■ hFE Classification

TYPE	BCX54	BCX54-10	BCX54-16
Marking	BA	BC	BD

TYPE	BCX55	BCX55-10	BCX55-16
Marking	BE	BG	BM

TYPE	BCX56	BCX56-10	BCX56-16
Marking	BH	BK	BL

■ Package mechanical data



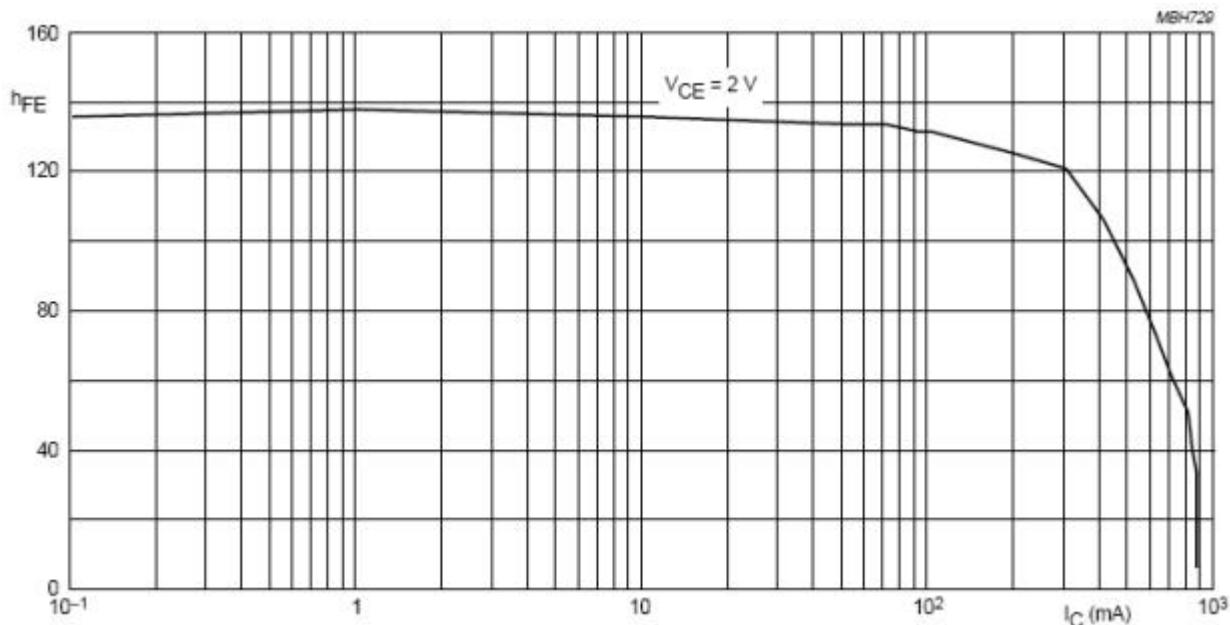
Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	1.4		1.6	0.055		0.063
b	0.35		0.52	0.013		0.197
b1	0.4		0.58	0.016		0.023
c	0.35		0.44	0.014		0.017
D	4.4		4.6	0.173		0.181
D1		1.55				0.061
E	2.35		2.55	0.091		0.102
E1	3.94		4.25	0.155		0.167
e		1.500				0.060
e1		3.000				0.118
L	0.9		1.1	0.035		0.047



Jiangsu Weida Semiconductor Co., Ltd.

NPN Transistors

■ Typical Characteristics



Information furnished in this document is believed to be accurate and reliable. However, Jiangsu Weida Semiconductor Co., Ltd assumes no responsibility for the consequences of use without consideration for such information nor use beyond it.

Information mentioned in this document is subject to change without notice, apart from that when an agreement is signed, Jiangsu Weida Semiconductor Co., Ltd complies with the agreement.

Products and information provided in this document have no infringement of patents. Jiangsu Weida Semiconductor Co., Ltd assumes no responsibility for any infringement of other rights of third parties which may result from the use of such products and information.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Bipolar Transistors - BJT category:

Click to view products by Weida Semiconductor manufacturer:

Other Similar products are found below :

[BC559C](#) [MCH4017-TL-H](#) [MMBT-2369-TR](#) [BC546/116](#) [NJVMJD148T4G](#) [NTE16](#) [NTE195A](#) [IMX9T110](#) [2N4401-A](#) [2N6728](#) [2SA1419T-TD-H](#) [2SB1204S-TL-E](#) [2SC5488A-TL-H](#) [FMC5AT148](#) [2N2369ADCSM](#) [2N2907A](#) [2N3904-NS](#) [2N5769](#) [2SC4618TLN](#) [CPH6501-TL-E-US6T6TR](#) [BAX18/A52R](#) [BC556/112](#) [IMZ2AT108](#) [MMST8098T146](#) [MCH6102-TL-E](#) [BC846B-13-F](#) [2N3879](#) [30A02MH-TL-E](#) [NTE13NTE282](#) [NTE323](#) [NTE350](#) [NTE81](#) [JANTX2N2920L](#) [JANSR2N2907AUB](#) [CMLT3946EG TR](#) [SNSS40600CF8T1G](#) [CMLT3906EG TR](#) [GRP-DATA-JANS2N2907AUB](#) [GRP-DATA-JANS2N2222AUA](#) [MMDT3946FL3-7](#) [2N4240](#) [JANS2N3019](#) [MSB30KH-13](#) [2N2221AUB](#) [2SD1815T-TL-E](#) [2N6678](#) [2N2907Ae4](#) [JAN2N3507](#)